

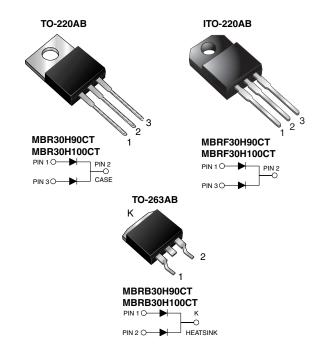
Vishay General Semiconductor

RoHS

COMPLIANT

Dual Common-Cathode High-Voltage Schottky Rectifier

High Barrier Technology for Improved High Temperature Performance



PRIMARY CHARACTERISTICS					
I _{F(AV)}	15 A x 2				
V _{RRM}	90 V, 100 V				
I _{FSM}	275 A				
V _F	0.67 V				
I _R	5.0 μA				
T _J max.	175 °C				

FEATURES

- Guardring for overvoltage protection
- Lower power losses, high efficiency
- Low forward voltage drop
- Low leakage current
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 260 °C, 40 s (for TO-220AB and ITO-220AB package)
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, dc-to-dc converters or polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	MBR30H90CT	MBR30H100CT	UNIT		
Maximum repetitive peak reverse voltage	V _{RRM}	90	100	V		
Working peak reverse voltage	V _{RWM}	90	100	V		
Maximum DC blocking voltage	V _{DC}	90	100	V		
Maximum average forward rectified current (Fig. 1) total device per diode	I _{F(AV)}	30 15		А		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	275		А		
Peak repetitive reverse current per diode at $t_p = 2 \ \mu s$, 1 kHz	I _{RRM}	1.0		А		
Voltage rate of change (rated V _R)	dV/dt	10 000		V/µs		
Operating junction and storage temperature range	T _J , T _{STG}	- 65 to + 175		°C		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V _{AC}	1500		V		

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ELECTRICAL CHARACTERISTICS ($T_C = 25$ °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT		
Maximum instantaneous forward voltage per diode ⁽¹⁾	$I_{F} = 15 \text{ A}$ $I_{F} = 15 \text{ A}$ $I_{F} = 30 \text{ A}$ $I_{F} = 30 \text{ A}$	$T_{J} = 25 °C$ $T_{J} = 125 °C$ $T_{J} = 25 °C$ $T_{J} = 125 °C$ $T_{J} = 125 °C$	V _F	0.82 0.67 0.93 0.80	V		
Maximum reverse current at rated $\rm V_R$ per diode $^{(2)}$		T _J = 25 °C T _J = 125 °C	I _R	5.0 6.0	μA mA		

Notes:

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS ($T_C = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT	
Typical thermal resistance per diode	$R_{ ext{ heta}JC}$	1.9	4.6	1.9	°C/W	

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	MBR30H100CT-E3/45	1.85	45	50/tube	Tube		
ITO-220AB	MBRF30H100CT-E3/45	1.99	45	50/tube	Tube		
TO-263AB	MBRB30H100CT-E3/45	1.35	45	50/tube	Tube		
TO-263AB	MBRB30H100CT-E3/81	1.35	81	800/reel	Tape and reel		
TO-220AB	MBR30H100CTHE3/45 (1)	1.85	45	50/tube	Tube		
ITO-220AB	MBRF30H100CTHE3/45 (1)	1.99	45	50/tube	Tube		
TO-263AB	MBRB30H100CTHE3/45 (1)	1.35	45	50/tube	Tube		
TO-263AB	MBRB30H100CTHE3/81 (1)	1.35	81	800/reel	Tape and reel		

Note:

(1) Automotive grade AEC Q101 qualified

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

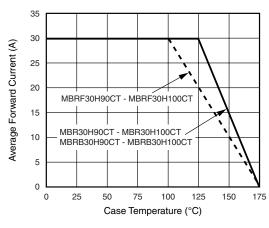
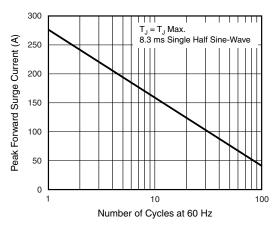


Figure 1. Forward Derating Curve Per Diode





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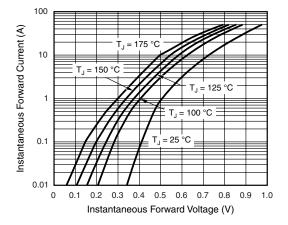


Figure 3. Typical Instantaneous Forward Characteristics Per Diode

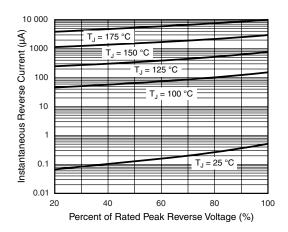


Figure 4. Typical Reverse Characteristics Per Diode

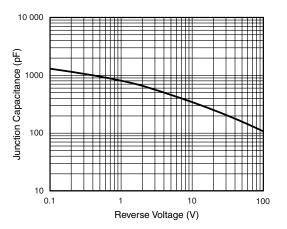


Figure 5. Typical Junction Capacitance Per Diode

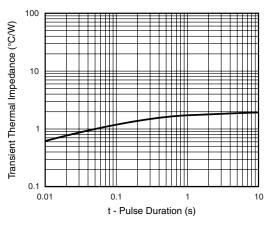


Figure 6. Typical Transient Thermal Impedance Per Diode

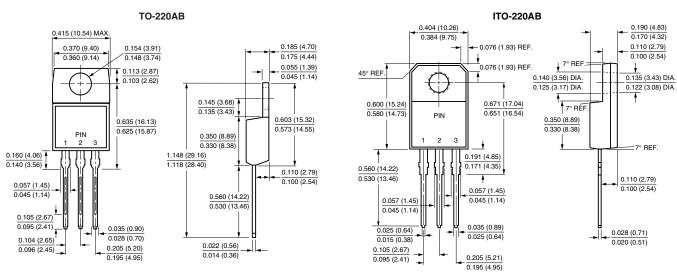
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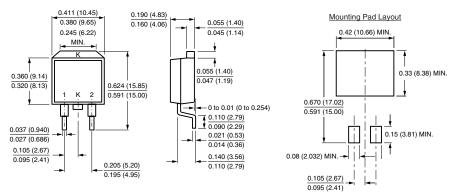
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



TO-263AB



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